

# HD74LS156

## Dual 2-line-to-4-line Decoders / Demultiplexers (with open collector outputs)

REJ03D0441-0300

Rev.3.00

Jul.13.2005

This circuit features dual 1-line-to-4-line demultiplexer with individual strobes and common binary-address input. When both sections are enabled by the strobes, the common binary-address inputs sequentially select and route associated input data to the appropriate output of each section. The individual strobes permit activating or inhibiting each of the 4-bit sections as desired. Data applied to input 1C is inverted through its outputs. The inverter following the 1C data input permits use as a 3-to-8-line decoder or 1-to-8-line demultiplexer without external gating.

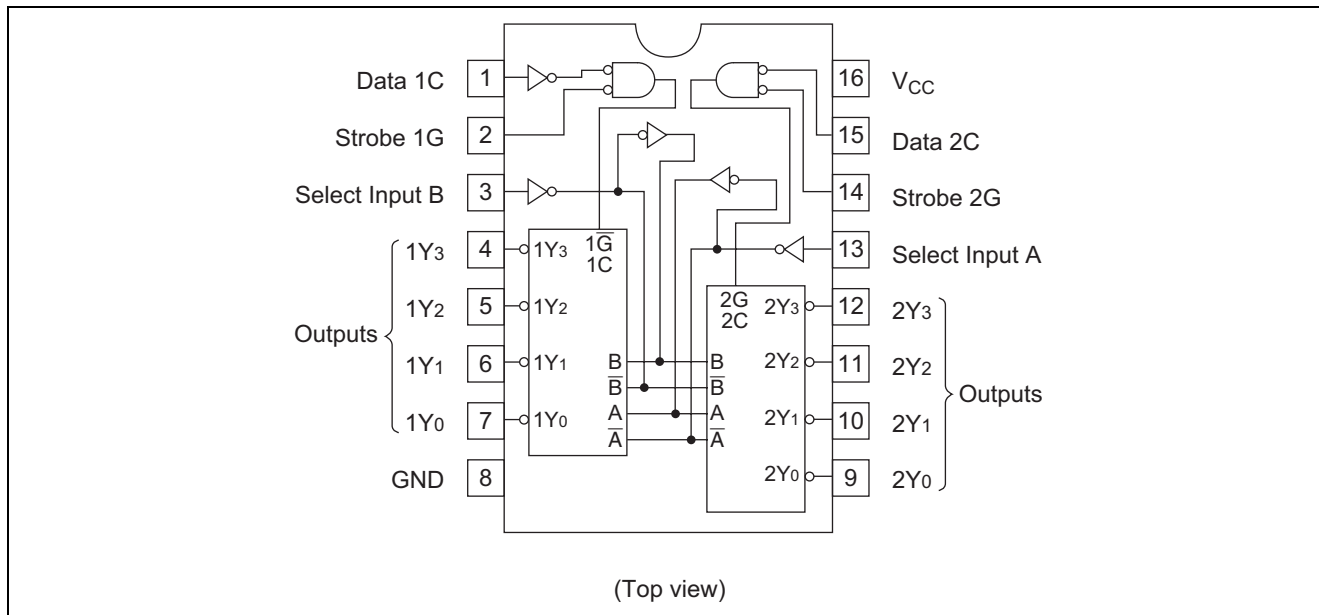
### Features

- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74LS156P	DILP-16 pin	PRDP0016AE-B (DP-16FV)	P	—
HD74LS156RPEL	SOP-16 pin (JEDEC)	PRSP0016DG-A (FP-16DNV)	FP	EL (2,500 pcs/reel)

Note: Please consult the sales office for the above package availability.

### Pin Arrangement



## Function Table

### • 2-to-4-line Decoder / 1-to-4-line Demultiplexer

Inputs				Outputs			
Select		Strobe	Data	1Y <sub>0</sub>	1Y <sub>1</sub>	1Y <sub>2</sub>	1Y <sub>3</sub>
B	A	1G	1C				
X	X	H	X	H	H	H	H
L	L	L	H	L	H	H	H
L	H	L	H	H	L	H	H
H	L	L	H	H	H	L	H
H	H	L	H	H	H	H	L
X	X	X	L	H	H	H	H

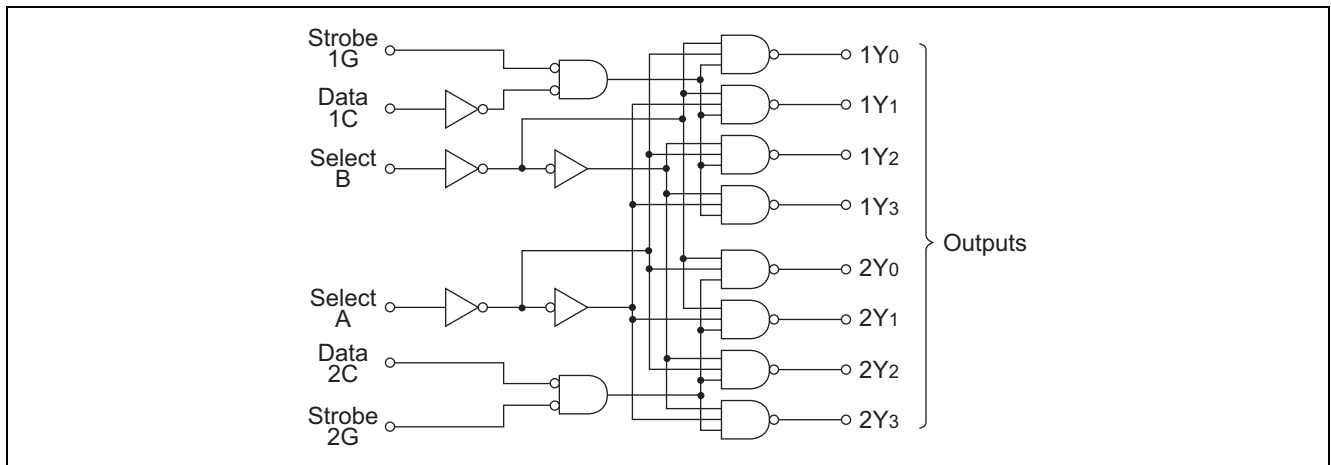
Inputs				Outputs			
Select		Strobe	Data	2Y <sub>0</sub>	2Y <sub>1</sub>	2Y <sub>2</sub>	2Y <sub>3</sub>
B	A	2G	2C				
X	X	H	X	H	H	H	H
L	L	L	L	L	H	H	H
L	H	L	L	H	L	H	H
H	L	L	L	H	H	L	H
H	H	L	L	H	H	H	L
X	X	X	H	H	H	H	H

### • 3-to-8-line Decoder / 1-to-8-line Demultiplexer

Inputs				Outputs							
Select			Strobe or Data	(0)	(1)	(2)	(3)	(4)	(5)	(6)	(7)
C* <sup>1</sup>	B	A	G* <sup>2</sup>	2Y <sub>0</sub>	2Y <sub>1</sub>	2Y <sub>2</sub>	2Y <sub>3</sub>	1Y <sub>0</sub>	1Y <sub>1</sub>	1Y <sub>2</sub>	1Y <sub>3</sub>
X	X	X	H	H	H	H	H	H	H	H	H
L	L	L	L	L	H	H	H	H	H	H	H
L	L	H	L	H	L	H	H	H	H	H	H
L	H	L	L	H	H	L	H	H	H	H	H
L	H	H	L	H	H	H	L	H	H	H	H
H	L	L	L	H	H	H	H	L	H	H	H
H	L	H	L	H	H	H	H	H	L	H	H
H	H	L	L	H	H	H	H	H	H	L	H
H	H	H	L	H	H	H	H	H	H	H	L

- Notes: 1. C; input 1C and 2C connected together  
 2. G; inputs 1G and 2G connected together  
 3. H; high level, L; low level, X; irrelevant

## Block Diagram



## Absolute Maximum Ratings

Item	Symbol	Ratings	Unit
Supply voltage	$V_{CC}$	7	V
Input voltage	$V_{IN}$	7	V
Power dissipation	$P_T$	400	mW
Storage temperature	$T_{stg}$	-65 to +150	°C

Note: Voltage value, unless otherwise noted, are with respect to network ground terminal.

## Recommended Operating Conditions

Item	Symbol	Min	Typ	Max	Unit
Supply voltage	$V_{CC}$	4.75	5.00	5.25	V
High level output voltage	$V_{OH}$	—	—	5.5	V
Low level output current	$I_{OL}$	—	—	8	mA
Operating temperature	$T_{opr}$	-20	25	75	°C

## Electrical Characteristics

( $T_a = -20$  to  $+75$  °C)

Item	Symbol	min.	typ.*	max.	Unit	Condition
Input voltage	$V_{IH}$	2.0	—	—	V	
	$V_{IL}$	—	—	0.8	V	
Output current	$I_{OH}$	—	—	100	μA	$V_{CC} = 4.75$ V, $V_{IH} = 2$ V, $V_{IL} = 0.8$ V, $V_{OH} = 5.5$ V
Output voltage	$V_{OL}$	—	—	0.4	V	$I_{OL} = 4$ mA, $V_{CC} = 4.75$ V, $V_{IH} = 2$ V, $V_{IL} = 0.8$ V
		—	—	0.5		
Input current	$I_{IH}$	—	—	20	μA	$V_{CC} = 5.25$ V, $V_I = 2.7$ V
	$I_{IL}$	—	—	-0.4	mA	$V_{CC} = 5.25$ V, $V_I = 0.4$ V
	$I_I$	—	—	0.1	mA	$V_{CC} = 5.25$ V, $V_I = 7$ V
Supply current**	$I_{CC}$	—	6.1	10	mA	$V_{CC} = 5.25$ V
Input clamp voltage	$V_{IK}$	—	—	-1.5	V	$V_{CC} = 4.75$ V, $I_{IN} = -18$ mA

Notes: \*  $V_{CC} = 5$  V,  $T_a = 25$  °C

\*\*  $I_{CC}$  is measured with outputs open, A, B, and 1C inputs at 4.5 V, and 2C, 1G, and 2G inputs grounded.

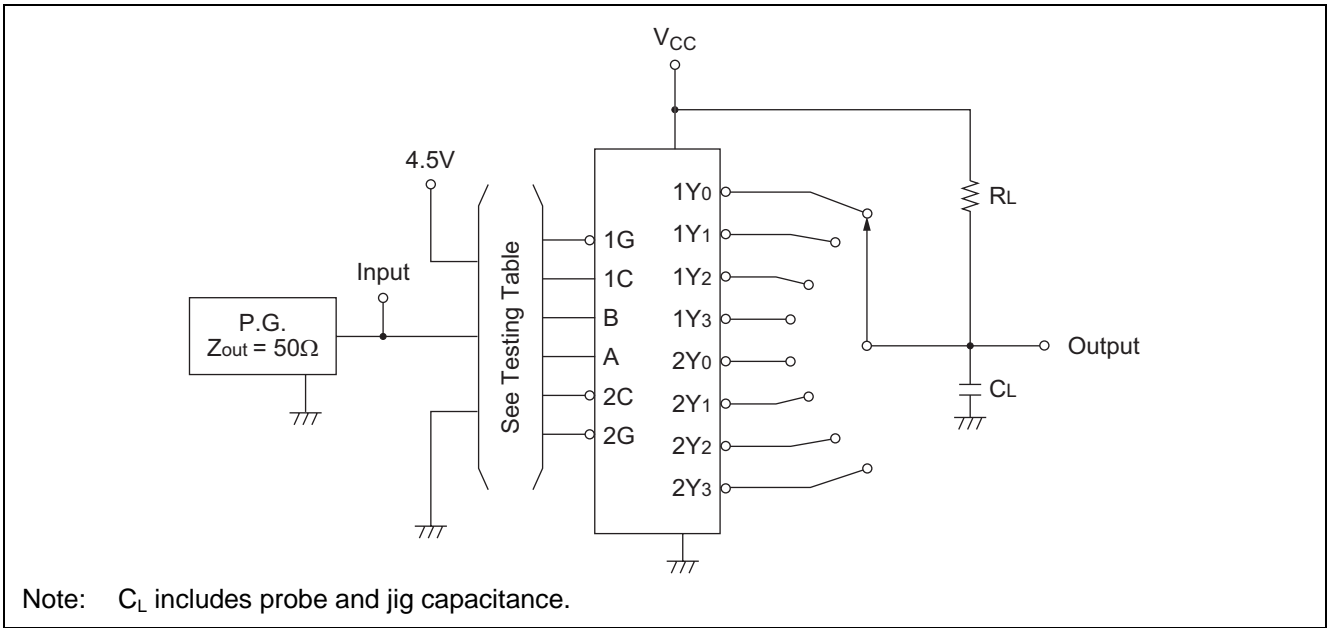
Switching Characteristics

(V<sub>CC</sub> = 5 V, Ta = 25°C)

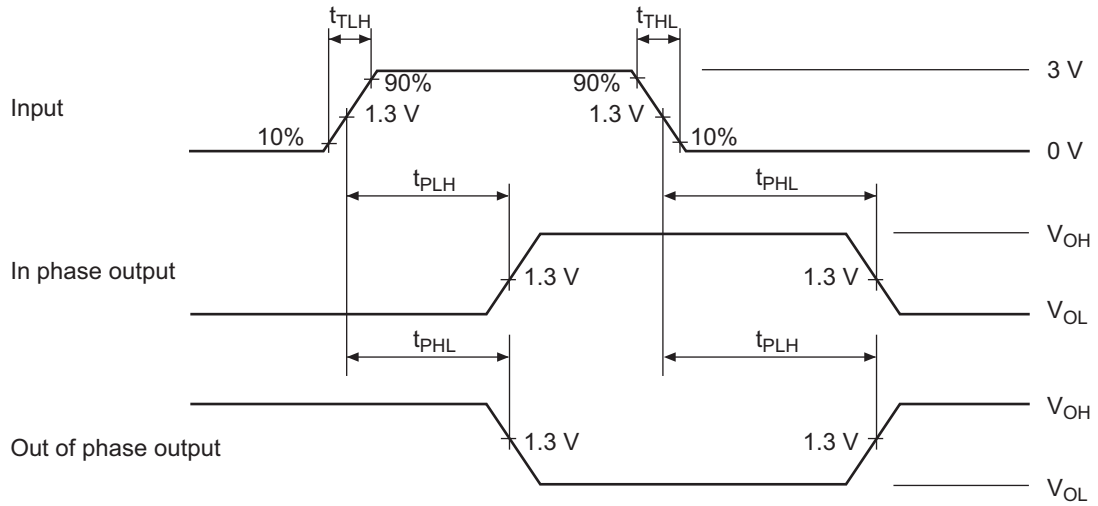
Item	Symbol	Inputs	Output	Level of logic	min.	typ.	max.	Unit	Condition
Propagation delay time	t <sub>PLH</sub>	A, B, 2C, 1G or 2G	Y	2	—	25	40	ns	C <sub>L</sub> = 15 pF, R <sub>L</sub> = 2 kΩ
	t <sub>PHL</sub>	A, B, 2C, 1G or 2G	Y	2	—	34	51		
	t <sub>PLH</sub>	A or B	Y	3	—	31	46		
	t <sub>PHL</sub>	A or B	Y	3	—	34	51		
	t <sub>PLH</sub>	1C	Y	3	—	32	48		
	t <sub>PHL</sub>	1C	Y	3	—	32	48		

Testing Method

Test Circuit

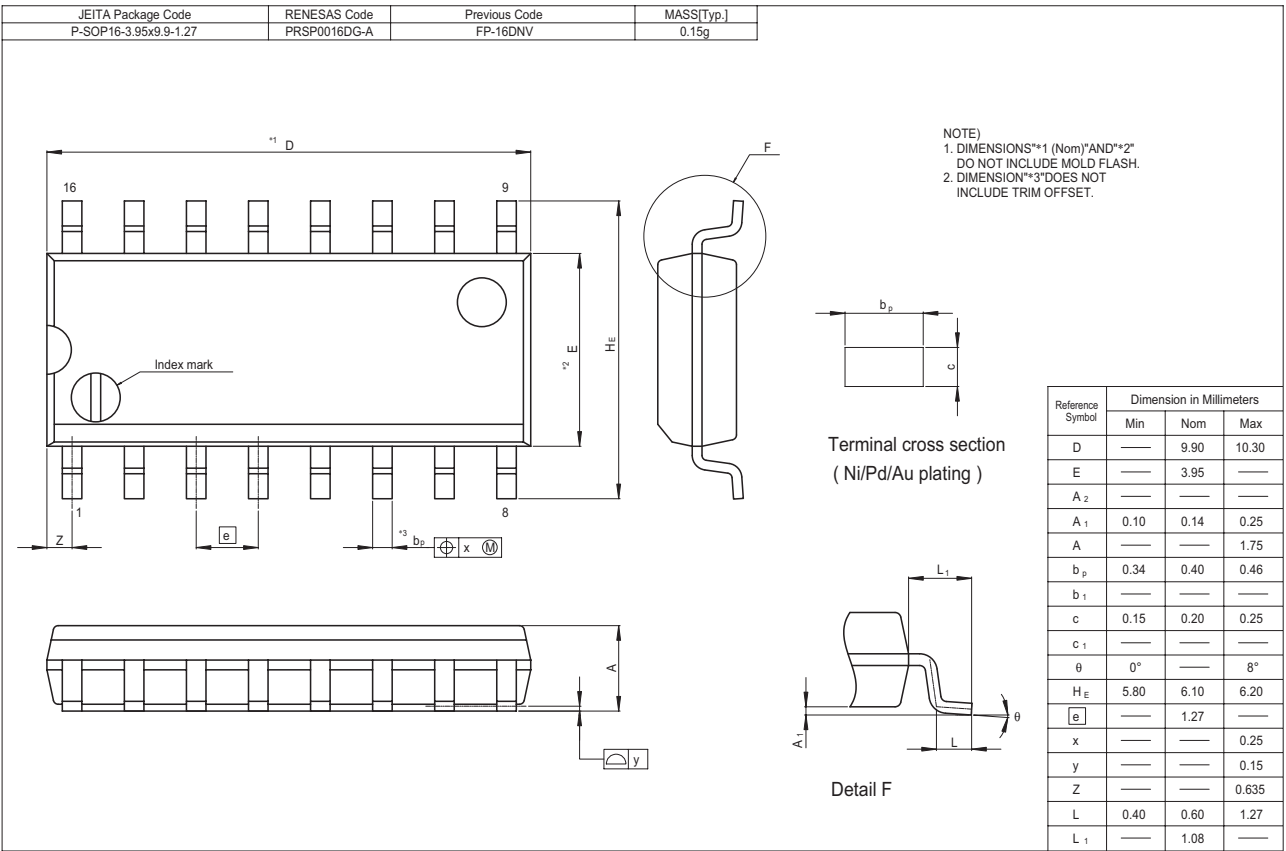
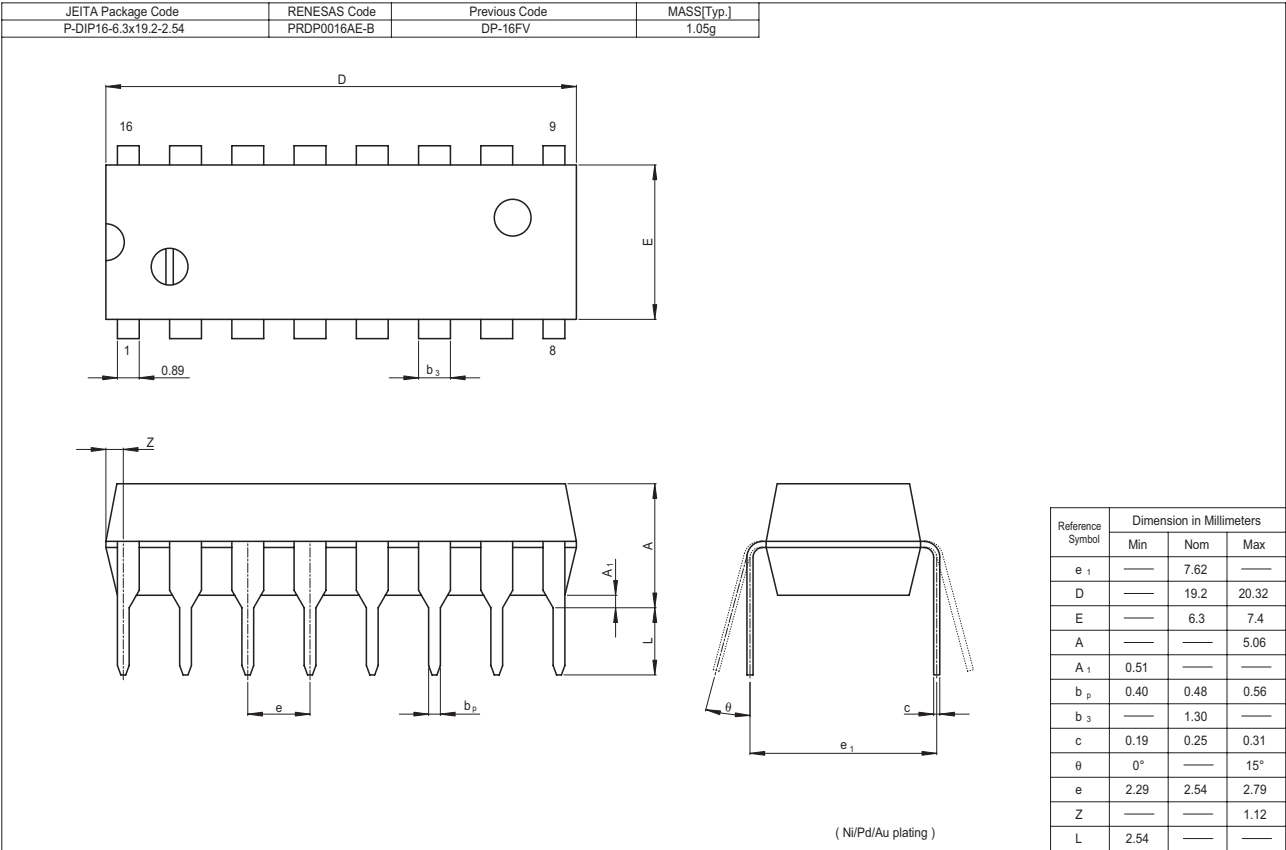


Waveform



Note: Input pulse;  $t_{TLH} \leq 15$  ns,  $t_{THL} \leq 6$  ns, PRR = 1 MHz, duty cycle 50%

Package Dimensions



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